

	L #	Hits	Search Text	DBs	Time Stamp
1	L1	17020	(trench groove grooved) near3 (oxide dioxide isolation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/03/28 13:20
2	L8	1231	1 and resistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/03/28 13:20
3	L15	225	1 same resistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/03/28 13:20
4	L22	98	1 with resistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/03/28 14:01
5	L29	29303	(resistive resistivity resistor) near20 (isolation STI FOX field LOCOS)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/03/28 14:09
6	L36	25231	(resistive resistor) near20 (isolation STI FOX field LOCOS)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/03/28 14:04
7	L43	2951	(resistive resistor) near20 ((si or silicon) near3 (poly or polycrystalline))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/03/28 14:06
8	L50	3804	(resistive resistivity resistor) near20 ((si or silicon) near3 (poly or polycrystalline))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/03/28 14:06
9	L57	597	29 and 50	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/03/28 14:09
10	L64	1	57 and (dummy adj gate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/03/28 14:07
11	L71	92	57 and ((resistive resistivity resistor) near20 (spac\$3))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/03/28 14:10

	Document ID
1	US 6346736 B1
2	US 6319772 B1
3	US 6297126 B1
4	US 6265302 B1
5	US 6083785 A
6	US 5759886 A
7	US 5652176 A